MSKSEMI















ESD

TVS

TSS

MOV

GDT

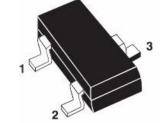
PLED

Broduct data speet



Features

- 2 Unidirectional Transil functions
- Low leakage current: I_{RM} max< 1 μA at V_{RM}
- 300W peak pulse power(8/20µs)



Complies with the following standards IEC61000-4-2

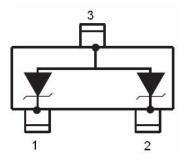
Level 4 15 kV (air discharge) 8 kV(contact discharge) MIL STD 883E - Method 3015-7 Class 3

25 kV HBM (Human Body Model)

Applications

- Computers
- **Printers**
- Communication systems

It is particularly recommended for the RS232 I/O port protection where the line interface withstands only with 2kV ESD surges.



SOT-23

Electrical Characteristics

	V	вк @	R @ IR IRM @ VRM		Rd	αΤ	С	V _F @	IF	
D/NI	min.	max.		max.		typ.	max.	typ.	max.	
P/N						note 1	note 2	0V bias		
	V	V	mA	μΑ	V	mΩ	10 ⁻⁴ /⊃C	pF	V	mA
ESDA5V3L-MS	5.3	5.9	1	2	3	280	5	220	1.25	200
ESDA6V1L-MS	6.1	7.2	1	20	5.25	350	6	140	1.25	200
ESDA14V2L-MS	14.2	15.8	1	5	12	650	10	90	1.25	200
ESDA25L-MS	25	30	1	1	24	1000	10	50	1.2	10

note 1 : Square pulse lpp = 15A, tp= $2.5\mu s$. **note 2**: \triangle VBR = α T* (Tamb -25°C) * VBR (25°C)

Absolute Ratings (T_{amb}=25°C)

Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (t _p = 8/20μs)	300	W
TL	Maximum lead temperature for soldering during 10s	260	°C
T _{stg}	Storage Temperature Range	-55 to +155	°C
T _{op}	Operating Temperature Range	-40 to +125	°C
Tj	Maximum junction temperature	150	°C
	Electrostatic discharge		
V _{PP}	MIL STD 883C -Method 3015-6	25	kV
	IEC61000-4-2 air discharge	15	r. V
	IEC61000-4-2 contact discharge	8	



Electrical Parameter

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ IPP
V_{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
I _T	Test Current
V_{BR}	Breakdown Voltage @ I⊤

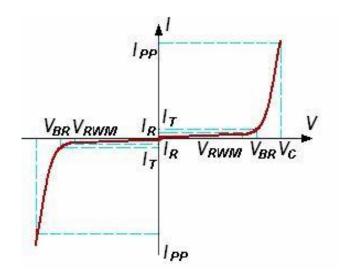


FIG1: Pulse Waveform

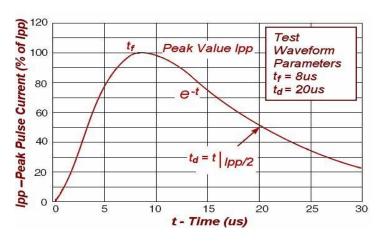
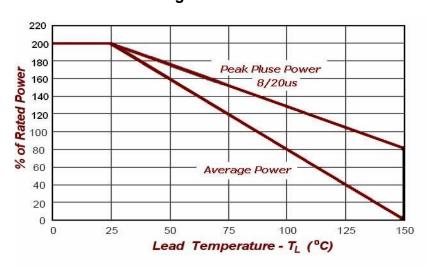


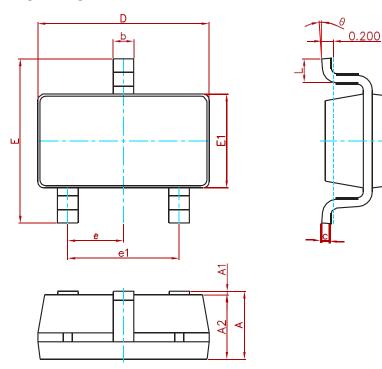
FIG2:Power Derating





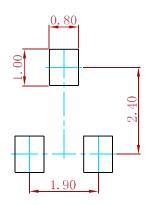
Semiconductor

PACKAGE MECHANICAL DATA



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
E	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
0	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.
 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
ESDAXXXL-MS	SOT-23	3000



Attention

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringementsof intellectual property rights or other rightsof third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.